

# Dual SPDT CMOS Analog Switch

## HI-5051/883

This CMOS analog switch offers low resistance switching performance for analog voltages up to the supply rails and for signal currents up to 70mA. "ON" resistance is low and stays reasonably constant over the full range of operating signal voltage and current.  $R_{ON}$  remains exceptionally constant for input voltages between +5V and -5V and currents up to 50mA. Switch impedance also changes very little over temperature, particularly between 0°C and +75°C.  $R_{ON}$  is nominally 25Ω.

The HI-5051/883 provides break-before-make switching and is TTL and CMOS compatible for maximum application versatility. Performance is further enhanced by Dielectric Isolation processing which insures latch-free operation with very low input and output leakage currents (0.8nA at +25°C). The HI-5051/883 switch also features very low power operation (1.5mW at +25°C). The HI-5051/883 is available in a 20 Ld CLCC package and operates over the -55°C to +125°C temperature range.

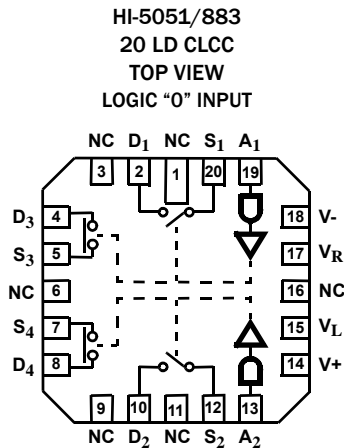
## Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Wide Analog Signal Range ..... ±15V
- Low "ON" Resistance ..... 25Ω (Typ), 50Ω (Max)
- High Current Capability ..... 70mA (Max)
- Break-Before-Make Switching
  - Turn-On Time ..... 370ns (Typ), 800ns (Max)
  - Turn-Off Time ..... 280ns (Typ), 400ns (Max)
- No Latch-Up
- Input MOS Gates are Protected from Electrostatic Discharge
- DTL, TTL, CMOS, PMOS Compatible

## Applications

- High Frequency Switching
- Sample and Hold
- Digital Filters
- Operational Amplifier Gain Switching

## Pin Configuration

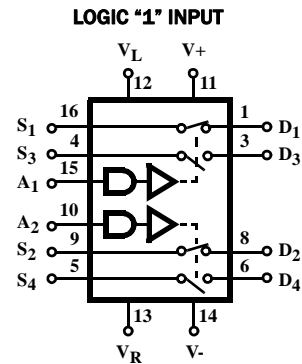


NOTE: Unused pins may be internally connected. Ground all unused pins.

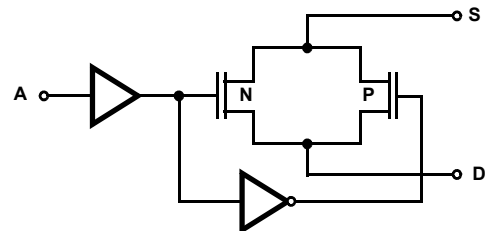
## Ordering Information

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
HI4-5051/883	HI4-5051 883	-55 to +125	20 Ld CLCC	J20.A

## Functional Diagram



### TYPICAL SWITCH



NOTE: Source and Drain are arbitrarily depicted as Analog Input and Output, respectively. They may be interchanged without affecting performance.

# HI-5051/883

## Absolute Maximum Ratings

Voltage Between V+ and V- Terminals	36V
$\pm V_{\text{SUPPLY}}$ to Ground (V+, V-)	$\pm 18\text{V}$
$V_{\text{R}}$ to Ground	$-V_{\text{SUPPLY}}$
$V_{\text{L}}$ to Ground	$+V_{\text{SUPPLY}}$
Digital and Analog Input Voltage ( $V_{\text{A}}$ , $V_{\text{S}}$ , $V_{\text{D}}$ )	$+V_{\text{SUPPLY}}$ +4V $-V_{\text{SUPPLY}}$ -4V
Peak Current (Source to Drain) (Pulse at 1ms, 10% Duty Cycle Max)	70mA
Continuous Current (Any Pin)	20mA
ESD Rating	<2000V

## Thermal Information

Thermal Resistance	$\theta_{\text{JA}}$ ( $^{\circ}\text{C}/\text{W}$ )	$\theta_{\text{JC}}$ ( $^{\circ}\text{C}/\text{W}$ )
CLCC Package	80	20
Package Power Dissipation at +75 $^{\circ}\text{C}$		
CLCC Package	1.0W	
Package Power Dissipation Derating Factor above +75 $^{\circ}\text{C}$		
CLCC Package	12.5mW/ $^{\circ}\text{C}$	
Junction Temperature	+175 $^{\circ}\text{C}$	
Storage Temperature Range	-65 $^{\circ}\text{C}$ to +150 $^{\circ}\text{C}$	
Lead Temperature (Soldering 10s)	+300 $^{\circ}\text{C}$	

## Recommended Operating Conditions

Operating Temperature Range	-55 $^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$
Operating Supply Voltage	$\pm 15\text{V}$
Logic Supply Voltage ( $V_{\text{L}}$ )	+5.0V
Logic Reference Voltage ( $V_{\text{R}}$ )	0.0V
Analog Input Voltage ( $V_{\text{S}}$ )	$\pm V_{\text{SUPPLY}}$
Address Low Level ( $V_{\text{AL}}$ )	0V to 0.8V
Address High Level ( $V_{\text{AH}}$ )	2.4V to +5.0V

**CAUTION:** Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

**TABLE 1. D.C. ELECTRICAL PERFORMANCE SPECIFICATIONS**

Device Tested at: Supply Voltage =  $\pm 15\text{V}$ ,  $V_{\text{L}}$  = +5.0V,  $V_{\text{R}}$  = 0.0V,  $V_{\text{AH}}$  = 2.4V,  $V_{\text{AL}}$  = +0.8V, unused pins are grounded, unless otherwise specified.

D.C. PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE ( $^{\circ}\text{C}$ )	MIN	MAX	UNITS
Switch "ON" Resistance	$R_{\text{DS2}}$	$V_{\text{D}} = -10\text{V}$ , $I_{\text{S}} = 10\text{mA}$ S1/S2/S3/S4	1	+25	-	45	$\Omega$
			2, 3	-55 to +125	-	50	$\Omega$
		$V_{\text{D}} = 10\text{V}$ , $I_{\text{S}} = -10\text{mA}$ S1/S2/S3/S4	1	+25	-	45	$\Omega$
			2, 3	-55 to +125	-	50	$\Omega$
Source "OFF" Leakage Current	$I_{\text{S(OFF)}}$	$V_{\text{S}} = -10\text{V}$ , $V_{\text{D}} = 10\text{V}$ S1/S2/S3/S4	1	+25	-1	1	nA
			2, 3	-55 to +125	-100	100	nA
		$V_{\text{S}} = 10\text{V}$ , $V_{\text{D}} = -10\text{V}$ S1/S2/S3/S4	1	+25	-1	1	nA
			2, 3	-55 to +125	-100	100	nA
Drain "OFF" Leakage Current	$I_{\text{D(OFF)}}$	$V_{\text{D}} = -10\text{V}$ , $V_{\text{S}} = 10\text{V}$ S1/S2/S3/S4	1	+25	-1	1	nA
			2, 3	-55 to +125	-100	100	nA
		$V_{\text{D}} = 10\text{V}$ , $V_{\text{S}} = -10\text{V}$ S1/S2/S3/S4	1	+25	-1	1	nA
			2, 3	-55 to +125	-100	100	nA
Channel "ON" Leakage Current	$I_{\text{D(ON)}}$	$V_{\text{D}} = V_{\text{S}} = 10\text{V}$ S1/S2/S3/S4	1	+25	-2	2	nA
			2, 3	-55 to +125	-200	200	nA
		$V_{\text{D}} = V_{\text{S}} = -10\text{V}$ S1/S2/S3/S4	1	+25	-2	2	nA
			2, 3	-55 to +125	-200	200	nA
Low Level Address Current	$I_{\text{AL}}$	$V_{\text{A}} = 0\text{V}$ A1, A2	1	+25	-1	1	$\mu\text{A}$
			2, 3	-55 to +125	-10	1	$\mu\text{A}$
High Level Address Current	$I_{\text{AH}}$	$V_{\text{A}} = 2.4\text{V}$ , 5V A1, A2	1	+25	-1	1	$\mu\text{A}$
			2, 3	-55 to +125	-1	10	$\mu\text{A}$
Positive Supply Current	$+I_{\text{CC}}$	$V_{\text{A}} = 0\text{V}$ , 5V A1, A2	1	+25	-	200	$\mu\text{A}$
			2, 3	-55 to +125	-	300	$\mu\text{A}$
Negative Supply Current	$-I_{\text{CC}}$	$V_{\text{A}} = 0\text{V}$ , 5V A1, A2	1	+25	-200	-	$\mu\text{A}$
			2, 3	-55 to +125	-300	-	$\mu\text{A}$

# HI-5051/883

**TABLE 1. D.C. ELECTRICAL PERFORMANCE SPECIFICATIONS (Continued)**

Device Tested at: Supply Voltage =  $\pm 15V$ ,  $V_L = +5.0V$ ,  $V_R = 0.0V$ ,  $V_{AH} = 2.4V$ ,  $V_{AL} = +0.8V$ , unused pins are grounded, unless otherwise specified.

D.C. PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE (°C)	MIN	MAX	UNITS
Logic Supply Current	$+I_L$	$V_A = 0V, 5V$	1	+25	-	200	$\mu A$
			2, 3	-55 to +125	-	300	$\mu A$
Reference Supply Current	$+I_R$	$V_A = 0V, 5V$	1	+25	-200	-	$\mu A$
			2, 3	-55 to +125	-300	-	$\mu A$

**TABLE 2. A.C. ELECTRICAL PERFORMANCE SPECIFICATIONS**

Device Tested at: Supply Voltage =  $\pm 15V$ ,  $V_L = +5.0V$ ,  $V_R = 0.0V$ ,  $V_{AH} = +5.0V$ ,  $V_{AL} = +0.0V$ , unused pins are grounded, unless otherwise specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE (°C)	MIN	MAX	UNITS
Turn "ON" Time	$t_{ON}$	$V_S = 10V, -10V$ $C_L = 10pF$ $R_L = 1k\Omega$	11	-55	-	450	ns
			9	+25	-	500	ns
			10	+125	-	800	ns
Turn "OFF" Time	$t_{OFF}$	$V_S = 10V, -10V$ $C_L = 10pF$ $R_L = 1k\Omega$	11	-55	-	350	ns
			9	+25	-	450	ns
			10	+125	-	600	ns

**TABLE 3. ELECTRICAL PERFORMANCE SPECIFICATIONS (NOTE 1)**

Device Characterized at: Supply Voltage =  $\pm 15V$ ,  $V_L = +5.0V$ ,  $V_R = 0.0V$ ,  $V_{AH} = 4.0V$ ,  $V_{AL} = 0.8V$ , unused pins are grounded, unless otherwise specified.

PARAMETERS	SYMBOL	CONDITIONS	NOTE	TEMPERATURE (°C)	MIN	MAX	UNITS
"ON" Resistance Match (Channel to Channel)	$R_{ON2}$ Match	$V_D = \pm 10V$ $I_D = 10mA$	1	+25	-	10	$\Omega$
Address Capacitance	$C_A$	$V_A = 0V, 5V$	1	+25	-	45	pF
Switch Input Capacitance	$C_{S(OFF)}$	Switch Off: $V_A = 0V$	1	+25	-	60	pF
Switch Output Capacitance	$C_{D(OFF)}$	Switch Off: $V_A = 0V$	1	+25	-	60	pF
	$C_{D(ON)}$	Switch On: $V_A = 5V$	1	+25	-	60	pF
Drain to Source Capacitance	$C_{DS(OFF)}$	Switch Off: $V_A = 0V$	1	+25	-	10	pF
Off Isolation	$V_{ISO}$	$V_S = 2V_{P.P}$ @ $f = 100kHz$ , $R_L = 100\Omega$	1	+25	-	60	dB
Crosstalk	$V_{CT}$	$V_S = 2V_{P.P}$ @ $f = 100kHz$ , $R_L = 100\Omega$	1	+25	-	60	dB
Charge Transfer Error	$V_{CTE}$	$V_S = GND$ , $C_L = 0.01\mu F$ $V_A = 0V$ to $4V$ @ $f = 200kHz$	1	+25	-	30	mV

NOTE:

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.

**TABLE 4. ELECTRICAL TEST REQUIREMENTS**

MIL-STD-883 TEST REQUIREMENTS	SUBGROUPS (See Tables 1 and 2)
Interim Electrical Parameters (Pre Burn-in)	1
Final Electrical Test Parameters	1 (Note 2), 2, 3, 9, 10, 11
Group A Test Requirements	1, 2, 3, 9, 10, 11
Groups C & D Endpoints	1

NOTE:

- PDA applies to Subgroup 1 only.

Test Circuits

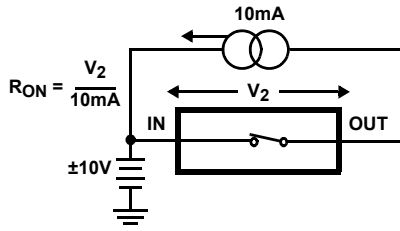


FIGURE 1.  $R_{DS}$

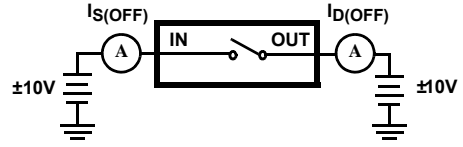


FIGURE 2.  $I_{S(OFF)}$

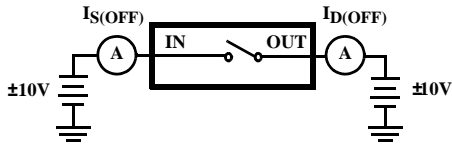


FIGURE 3.  $I_{D(OFF)}$

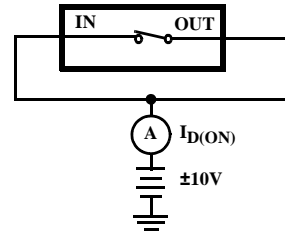


FIGURE 4.  $I_{D(ON)}$

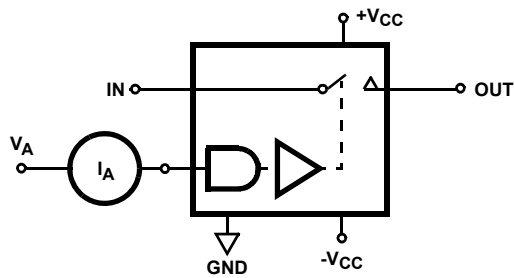


FIGURE 5. ADDRESS CURRENT

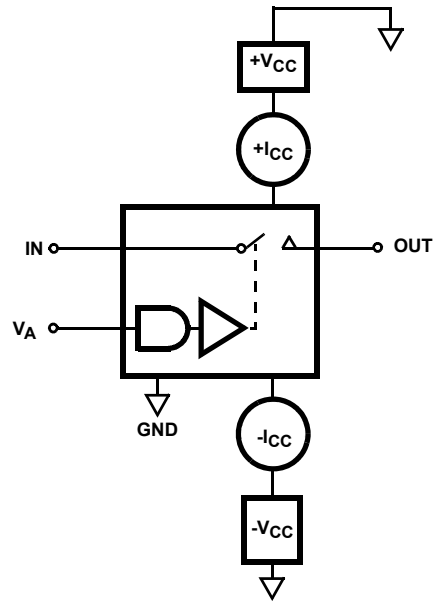


FIGURE 6. SUPPLY CURRENTS

**Test Circuits (Continued)**

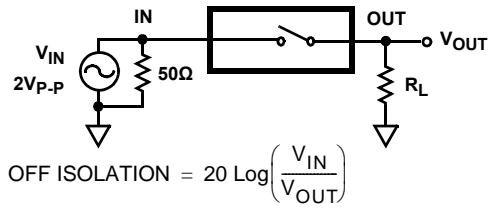
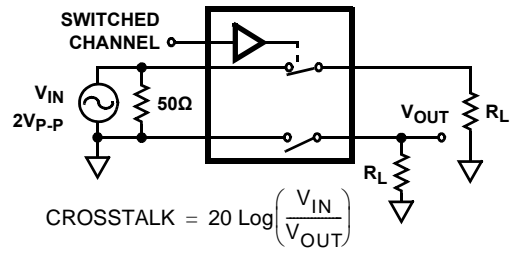
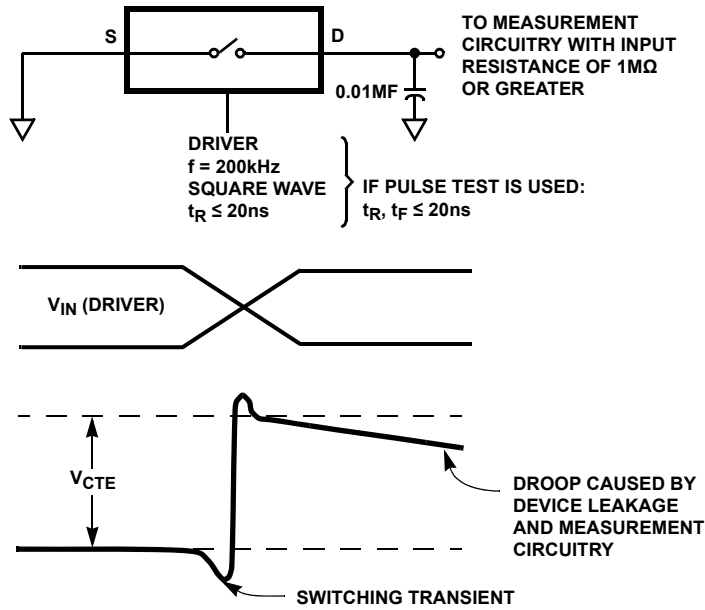


FIGURE 7. OFF ISOLATION



NOTE: Applies only to dual or double throw switches.

FIGURE 8. CROSSTALK



NOTE: V<sub>CTE</sub> may be a positive or negative value.

FIGURE 9. CHARGE TRANSFER

**Test Characteristics**

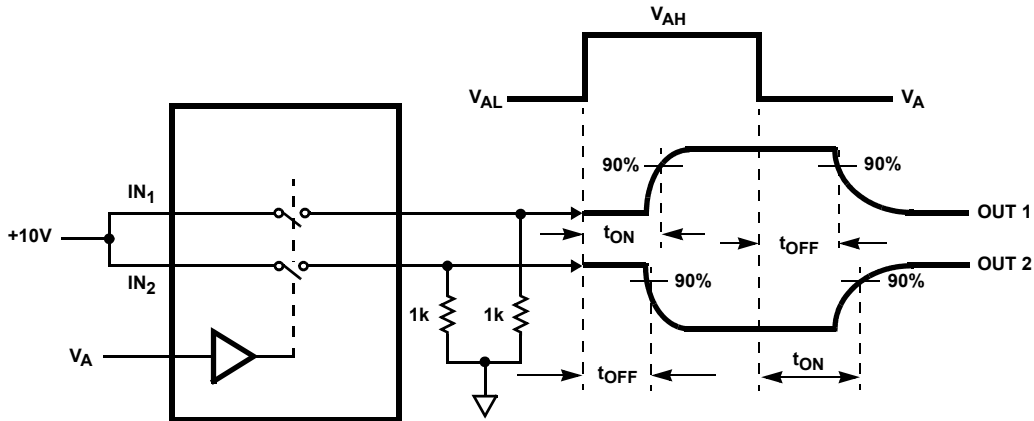


FIGURE 10. ON/OFF SWITCH TIME (t<sub>ON</sub>, t<sub>OFF</sub>)

**Test Characteristics** (Continued)

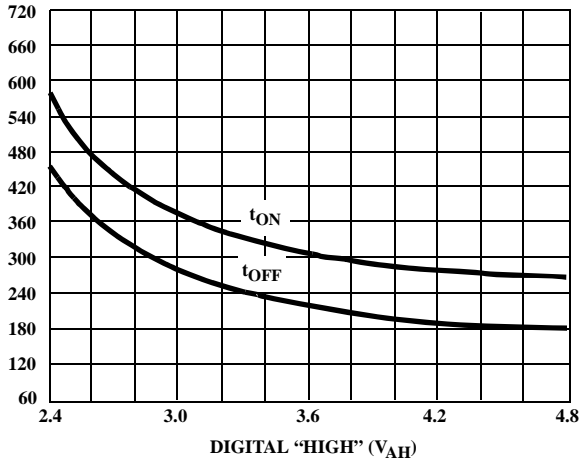


FIGURE 11. SWITCHING TIMES FOR DIGITAL TRANSITION

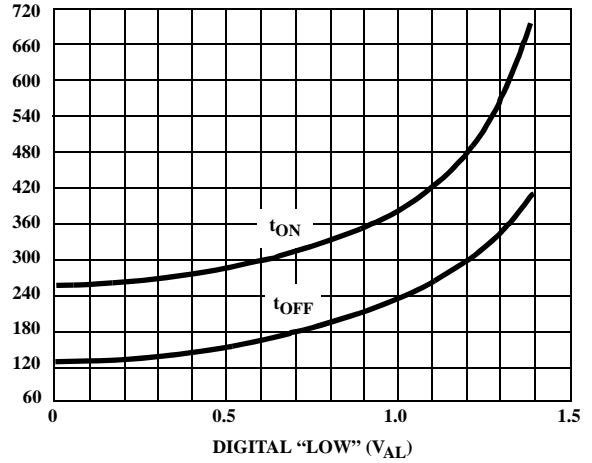
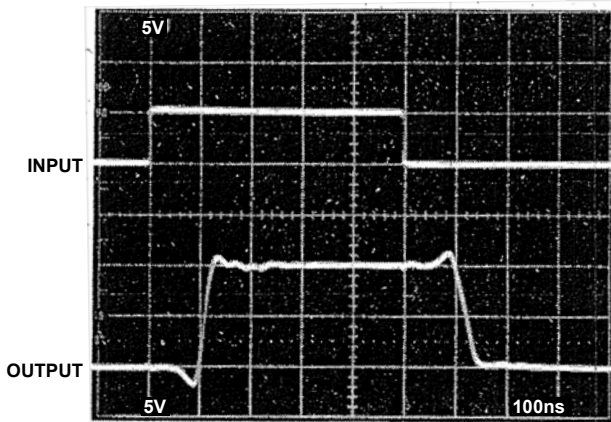


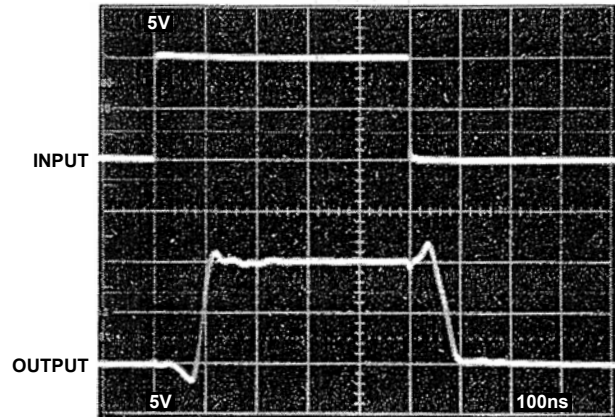
FIGURE 12. SWITCHING TIMES FOR NEGATIVE DIGITAL TRANSITION

**Test Waveforms**



Vertical Scale: Input = 5V/Div, (TTL; V<sub>AH</sub> = 5V, V<sub>AL</sub> = 0V)  
 Output = 5V/Div  
 Horizontal Scale: 100ns/Div

FIGURE 13.

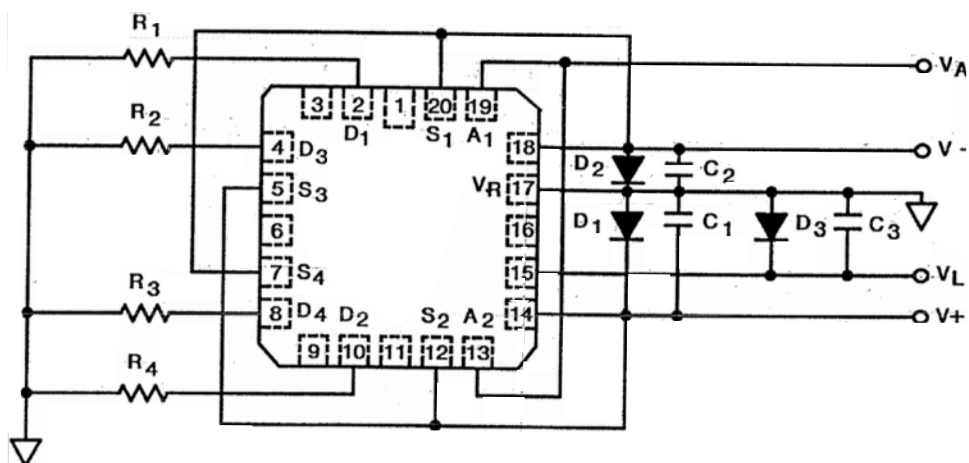


Vertical Scale: Input = 5V/Div, (CMOS; V<sub>AH</sub> = 10V, V<sub>AL</sub> = 0V)  
 Output = 5V/Div  
 Horizontal Scale: 100ns/Div

FIGURE 14.

## Burn-In Circuit

HI-5051/883 CERAMIC LCC



**NOTES:**

$R_1$  thru  $R_4 = 10k\Omega, \pm 5\%, 1/4W$  (Min)

$C_1, C_2, C_3 = 0.01\mu F/\text{Socket}$  (Min) or  $0.1\mu F/\text{Row}$ , (Min)

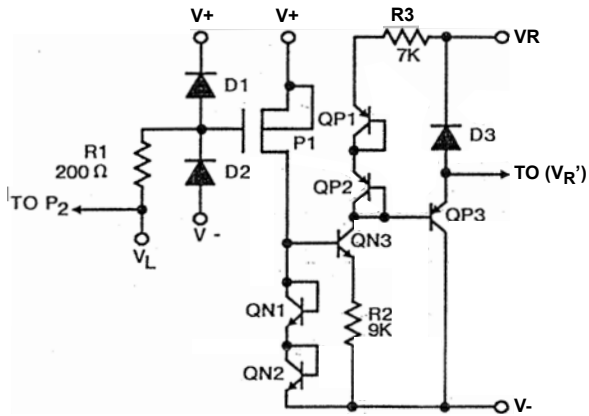
$D_1, D_2, D_3 = 1N4002$  or Equivalent/Board

$V_L = 5.5V \pm 0.5V$

$A_2 = A_2 = 5.5V \pm 0.5V$

$|V_+ - V_-| = 30V$

Schematic Diagrams



NOTE: Connect V+ to  $V_L$  for minimizing power consumption when driving from CMOS circuits.

FIGURE 15. TTL/CMOS REFERENCE CIRCUIT

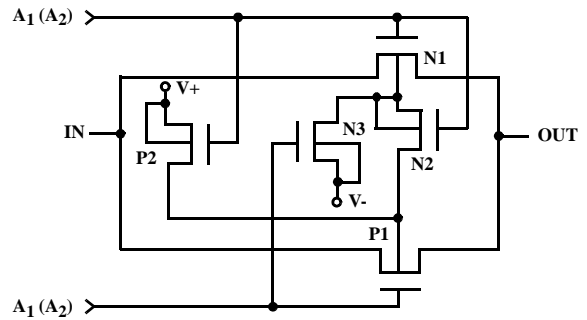
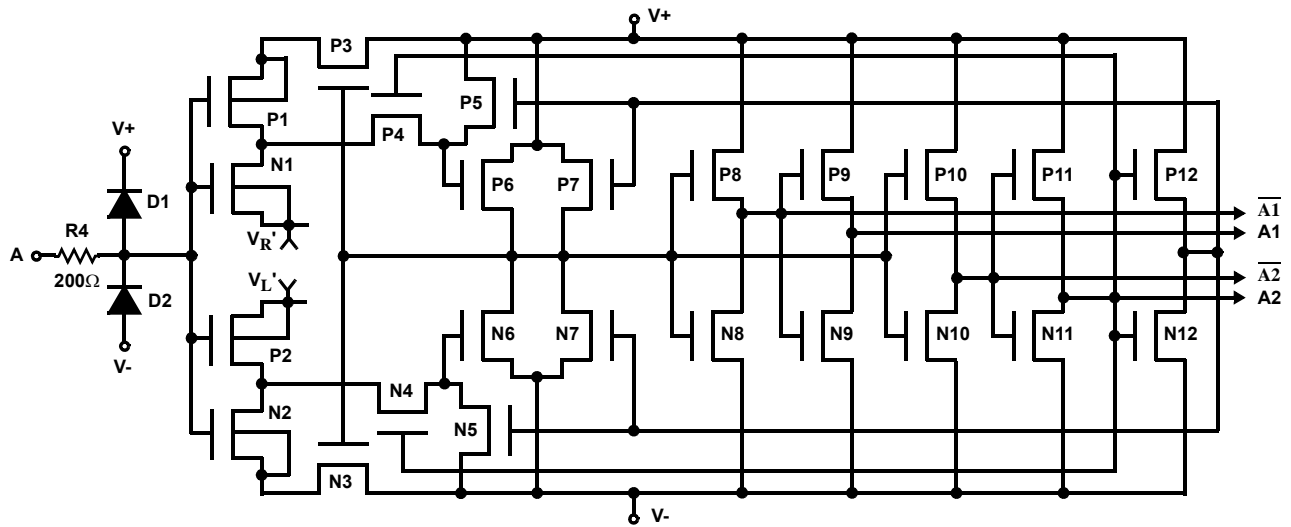


FIGURE 16. SWITCH CELL



NOTE: All N-Channel bodies to  $V_-$ , all P-Channel bodies to  $V_+$  except as shown.

DIGITAL INPUT BUFFER AND LEVEL SHIFTER



# HI-5051/883

## Die Characteristics

### DIE DIMENSIONS:

96mils x 81mils x 20mils  
(2430 $\mu$ m x 2050 $\mu$ m x 508 $\mu$ m)

### METALLIZATION:

Type: Aluminum  
Thickness: 16k $\text{\AA}$   $\pm$  2k $\text{\AA}$

### GLASSIVATION:

Type: Nitride over Silox  
Silox Thickness: 12k $\text{\AA}$   $\pm$  2k $\text{\AA}$   
Nitride Thickness: 3.5k $\text{\AA}$   $\pm$  1k $\text{\AA}$

### SUBSTRATE POTENTIAL (Powered-up): V-

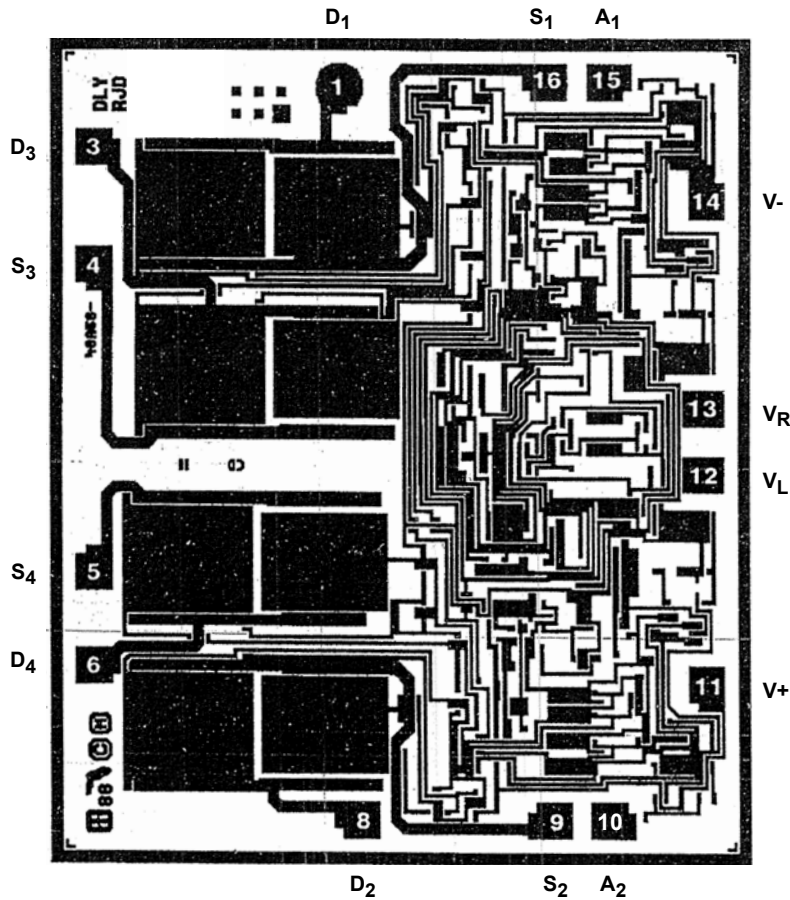
### DEVICE COUNT: 82

### WORST CASE CURRENT DENSITY:

1.0 x 10<sup>5</sup>A/cm<sup>2</sup> at 20mA

## Metallization Mask Layout

HI-5051/883



## Design Information

The information contained in this section has been developed through characterization and is for use as application and design information only. No guarantee is implied.

### Typical Performance Curves $T_A = +25^\circ\text{C}$ , $V_{\text{SUPPLY}} = \pm 15\text{V}$

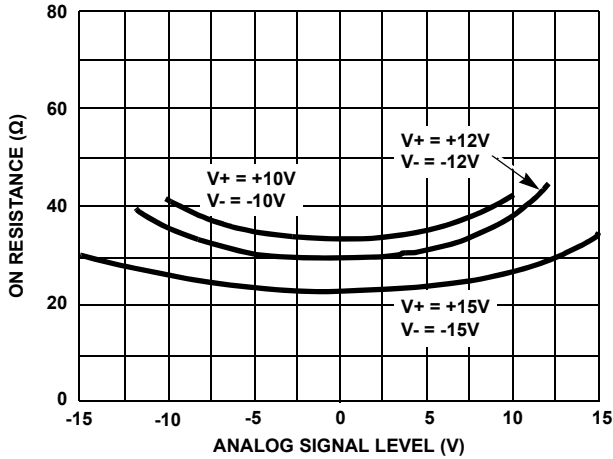


FIGURE 17. ON RESISTANCE vs ANALOG SIGNAL LEVEL AND POWER SUPPLY VOLTAGE

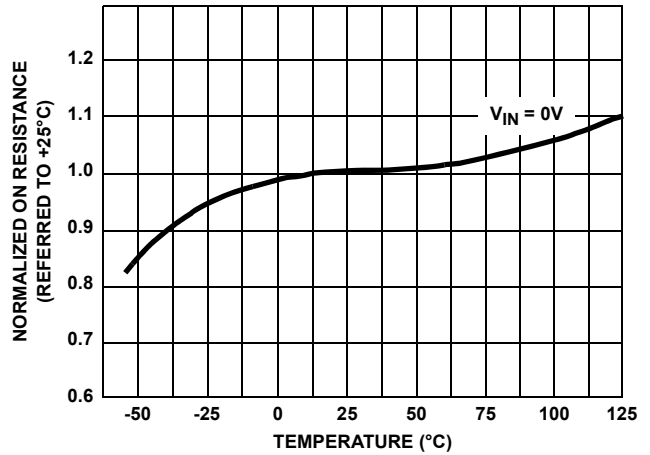


FIGURE 18. NORMALIZED ON RESISTANCE vs TEMPERATURE

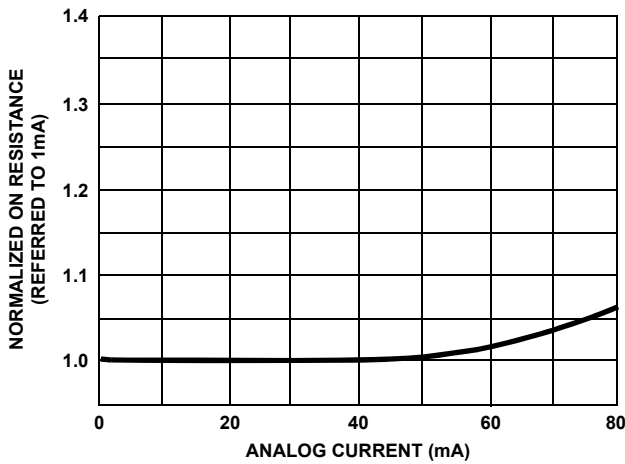


FIGURE 19. NORMALIZED ON RESISTANCE vs ANALOG CURRENT

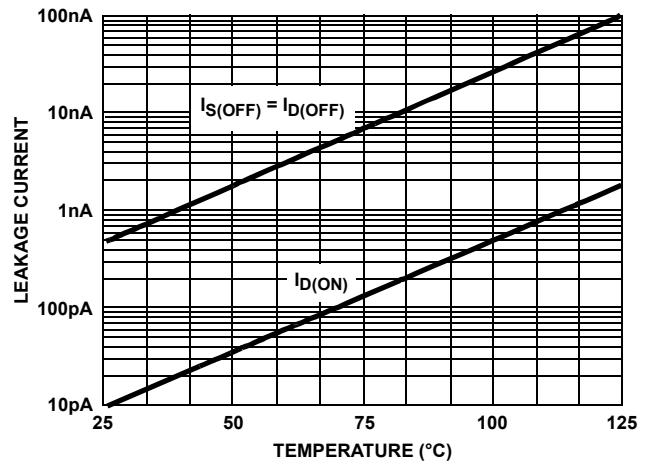


FIGURE 20. ON/OFF LEAKAGE CURRENTS vs TEMPERATURE

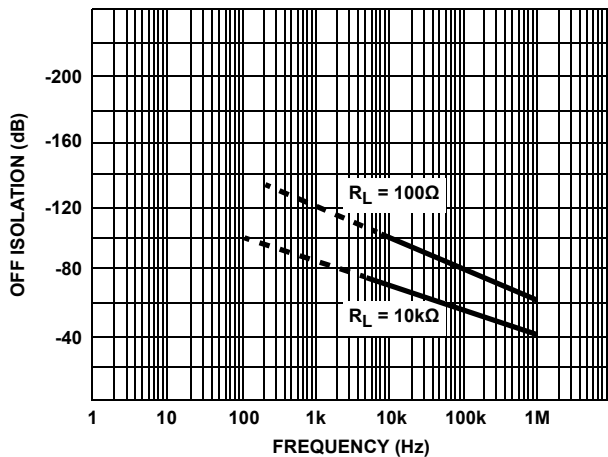


FIGURE 21. OFF ISOLATION vs FREQUENCY

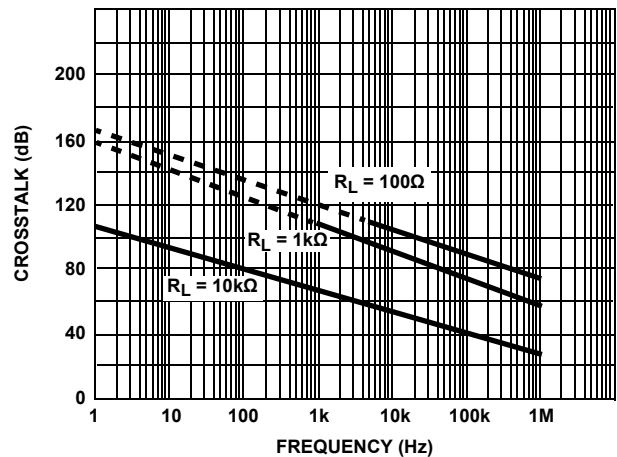
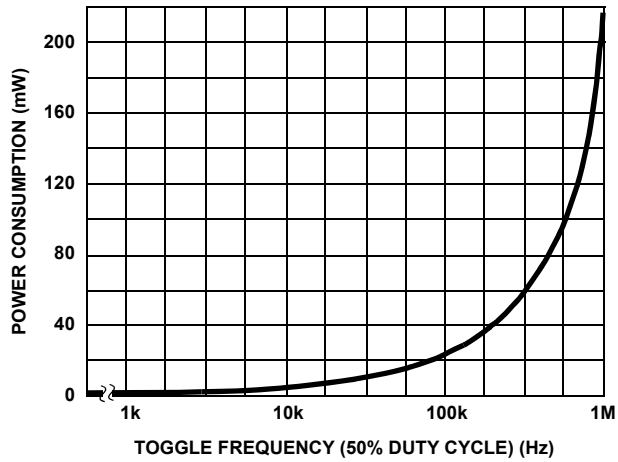


FIGURE 22. CROSSTALK vs FREQUENCY

**Design Information** The information contained in this section has been developed through characterization and is for use as application and design information only. No guarantee is implied.

**Typical Performance Curves**  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$  (Continued)



**FIGURE 23. POWER CONSUMPTION vs FREQUENCY**

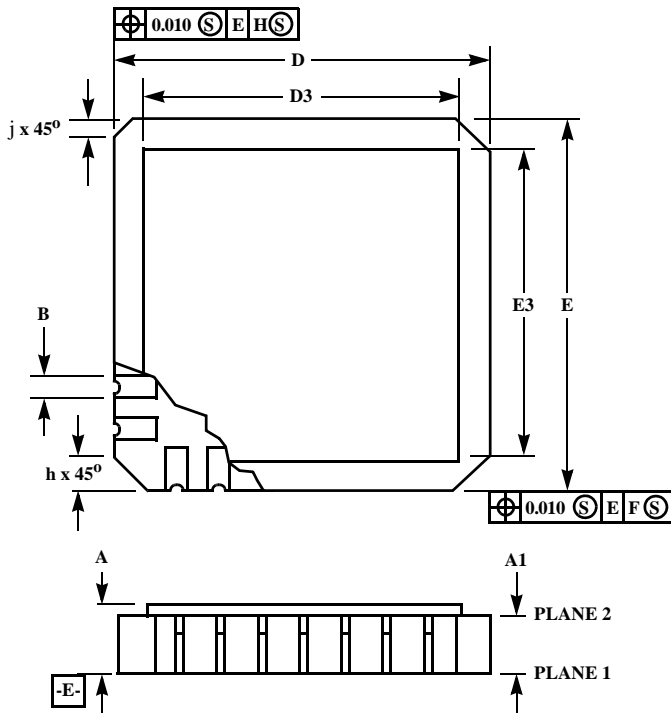
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## Ceramic Leadless Chip Carrier Packages (CLCC)



**J20.A MIL-STD-1835 CQCC1-N20 (C-2)**  
**20 PAD CERAMIC LEADLESS CHIP CARRIER PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.060	0.100	1.52	2.54	6, 7
A1	0.050	0.088	1.27	2.23	-
B	-	-	-	-	-
B1	0.022	0.028	0.56	0.71	2, 4
B2	0.072 REF		1.83 REF		-
B3	0.006	0.022	0.15	0.56	-
D	0.342	0.358	8.69	9.09	-
D1	0.200 BSC		5.08 BSC		-
D2	0.100 BSC		2.54 BSC		-
D3	-	0.358	-	9.09	2
E	0.342	0.358	8.69	9.09	-
E1	0.200 BSC		5.08 BSC		-
E2	0.100 BSC		2.54 BSC		-
E3	-	0.358	-	9.09	2
e	0.050 BSC		1.27 BSC		-
e1	0.015	-	0.38	-	2
h	0.040 REF		1.02 REF		5
j	0.020 REF		0.51 REF		5
L	0.045	0.055	1.14	1.40	-
L1	0.045	0.055	1.14	1.40	-
L2	0.075	0.095	1.91	2.41	-
L3	0.003	0.015	0.08	0.38	-
ND	5		5		3
NE	5		5		3
N	20		20		3

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**NOTES:**

1. Metallized castellations shall be connected to plane 1 terminals and extend toward plane 2 across at least two layers of ceramic or completely across all of the ceramic layers to make electrical connection with the optional plane 2 terminals.
2. Unless otherwise specified, a minimum clearance of 0.015 inch (0.38mm) shall be maintained between all metallized features (e.g., lid, castellations, terminals, thermal pads, etc.)
3. Symbol "N" is the maximum number of terminals. Symbols "ND" and "NE" are the number of terminals along the sides of length "D" and "E", respectively.
4. The required plane 1 terminals and optional plane 2 terminals (if used) shall be electrically connected.
5. The corner shape (square, notch, radius, etc.) may vary at the manufacturer's option, from that shown on the drawing.
6. Chip carriers shall be constructed of a minimum of two ceramic layers.
7. Dimension "A" controls the overall package thickness. The maximum "A" dimension is package height before being solder dipped.
8. Dimensioning and tolerancing per ANSI Y14.5M-1982.
9. Controlling dimension: INCH.

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